

Operational Amplifiers

Low Power Ground Sense **Operational Amplifiers**



LMR821G

General Description

Ground Sense Low Voltage Op-Amp integrates single Op-Amp on a single chip. Especially, these series are operable with low voltage and low supply current.

Features

- Low operating supply voltage
- Input Ground Sense, Output Full Swing
- High large signal voltage gain
- High Slew Rate
- Low supply current
- Low input offset voltage

Applications

- Customer electronics
- Buffer
- Active filter
- Mobile equipment

Simplified Schematic

Key Specifications

Low Operating Supply Voltage (single supply):

- +2.5V to +5.0V
- High voltage gain (RL= 600Ω): 105dB (Typ.) -40°C to +85°C
- Wide Temperature Range:
- High Slew Rate:
- Low Input Offset Voltage:
- Low Input Bias Current:

Package SSOP5

W(Typ.) xD(Typ.) xH(Max.) 2.90mm x 2.80mm x 1.25mm

2.0V/µs (Typ.)

3.5mV (Max.)

30nA (Typ.)

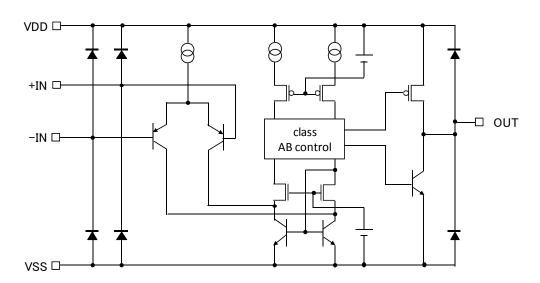
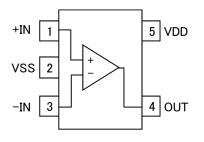


Figure 1. Simplified Schematic (1 channel only)

OProduct structure : Silicon monolithic integrated circuit OThis product is not designed protection against radioactive rays.

Pin Configuration

LMR821G (SSOP5)



Pin No.	Pin Name
1	+IN
2	VSS
3	-IN
4	OUT
5	VDD



Ordering Information

L	Μ	R	8	2	1	G	-	TR	
Part N LMR8	Number 321				Pack G:SS			Packaging and TR: Embossed (SSOP5)	forming specification tape and reel

●Line-up

Торг	Packa	age	Operable Part Number
-40°C to +85°C	SSOP5	Reel of 3000	LMR821G-TR

● Absolute Maximum Ratings(Ta=25°C)

Parameter	Sy	rmbol	Ratings	Unit
Supply Voltage	VDI	D-VSS	+7	V
Power dissipation	Pd	SSOP5	675 ^{*1*2}	mW
Differential Input Voltage ^{*3}		Vid	VDD to VSS	V
Input Common-mode Voltage Range	V	/icm	(VSS - 0.3) to (VDD + 0.3)	V
Operable with low voltage	١	/opr	+2.5 to +5.0	V
Operating Temperature	Г	Topr	- 40 to +85	ů
Storage Temperature	-	ſstg	- 55 to +150	°C
Maximum Junction Temperature	T	imax	+150	°C

Note: Absolute maximum rating item indicates the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out absolute maximum rated

temperature environment may cause deterioration of characteristics.

*1 To use at temperature above $Ta = 25^{\circ}C$ reduce 5.4mW/°C.

*2 Mounted on a FR4 glass epoxy PCB(70mm×70mm×1.6mm).

*3 The voltage difference between inverting input and non-inverting input is the differential input voltage. Then input terminal voltage is set to more than VSS.

•Electrical Characteristics:

OLMR821G (Unless otherwise specified VDD=+2.7V, VSS=0V)

Deremeter	Symbol	Temperature	,	Limits		Unit	Condition
Parameter	Symbol	Range	Min.	Тур.	Max.	Unit	Condition
Input Offset Voltage *4*5	Vio	25°C	-	1	3.5	mV	VDD=2.5V to 5.0V
input onset voltage	VIO	Full Range	-	-	4	IIIV	100-2.01 10 0.01
Input Offset Voltage Drift	ΔVio/ΔT	25°C	-	1	-	µV/°C	-
Input Offset Current ^{*4}	lio	25°C	-	0.5	30	nA	-
Input Bias Current *4	lb	25°C	-	30	90	nA	-
Supply Current ^{*5}		25°C	-	220	300		
Supply Current	IDD	Full range	-	-	500	μA	Av=0dB, VIN=1.35V
Maximum Output Voltage(High)	VOH	25°C	2.50	2.58	-	V	RL=600Ω to VDD/2
	VUH	25 C	2.60	2.66	-	v	RL=2kΩ to VDD/2
	VOL	25°C	-	130	200	mV	RL=600Ω to VDD/2
Maximum Output Voltage(Low)	VOL	25 C	-	80	120	mv	RL=2kΩ to VDD/2
Larga Signal Valtaga Cain	A.,	25°C	-	100	-	٩D	RL=600Ω to VDD/2
Large Signal Voltage Gain	Av	250	95	100	-	dB	RL=2kΩ to VDD/2
Input Common-mode Voltage Range	Vicm	25°C	VSS	-	VDD-0.9	V	VSS to VDD
Common-mode Rejection Ratio	CMRR	25°C	70	85	-	dB	VCM=0.5V
Power supply reject-ratio	PSRR	25°C	75	85	-	dB	VDD=2.7V to 5.0V VCM=1V
Output Source Current *6	Isource	25°C	12	16	-	mA	OUT=0V, short current
Output Sink Current *6	Isink	25°C	12	26	-	mA	OUT=2.7V, short current
Slew Rate	SR	25°C	-	1.5	-	V/µs	CL=25pF
Gain Bandwidth	GBW	25°C	-	4.5	-	MHz	CL=25pF, Av=40dB f=1MHz
Phase Margin	θ	25°C	-	45	-	Deg	CL=25pF, Av=40dB
Gain Margin	GM	25°C	-	4.5	-	dB	CL=25pF, Av=40dB
Input Referred Noise Voltage	Vn	25°C	-	45	-	nV/√Hz	f=1kHz
Total Harmonic Distortion + Noise	THD+N	25°C	-	0.01	-	%	OUT=2.2V _{P-P} , f=1kHz RL=10kΩ Av=0dB, DIN-AUDIO

*4 Absolute value.

*5 Full range: Ta=-40°C to +85°C

*6 Under the high temperature environment, consider the power dissipation of IC when selecting the output current.

When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

OLMR821G (Unless otherwise specified VDD=+2.5V, VSS=0V)

Parameter	Symbol	Temperature		Limits		- Unit	Condition	
Falameter	Symbol	Range	Min.	Тур.	Max.	Unit		
Input Offset Voltage *7	Vio	25°C	-	1	3.5	mV	VDD=2.5V to 5.0V	
input Onset voltage	VIO	Full Range	-	-	4	111V	VDD-2.5V 10 5.0V	
Maximum Output Voltage(High)	VOH	25°C	2.30	2.37	-	V	RL=600Ω to VDD/2	
	VОП	25 C	2.40	2.46	-	v	RL=2kΩ to VDD/2	
Maximum Output Voltage(Low)	VOL	25°C	-	130	200	mV	RL=600Ω to VDD/2	
Maximum Output Voltage(LOW)	VOL		-	80	120	IIIV	RL=2kΩ to VDD/2	

*7 Absolute value.

OLMR821G (Unless otherwise specified VDD=+5.0V, VSS=0V)

Parameter	Symbol	Temperature		Limits		Unit	Condition
Falameter	Symbol	Range	Min.	Тур.	Max.	Unit	Condition
Input Offset Voltage *8*9	Vio	25°C	-	1	3.5	mV	VDD=2.5V to 5.0V
input Onset voltage	10	Full Range	-	-	4	IIIV	VDD=2.5V 10 5.0V
Input Offset Voltage Drift	ΔVio/ΔT	25°C	-	1	-	µV/°C	-
Input Offset Current ^{*8}	lio	25°C	-	0.5	30	nA	-
Input Bias Current *8	lb	25°C	-	40	100	nA	-
Supply Current ^{*9}	IDD	25°C	-	300	400	μA	Av=0dB, VIN=2.5V
Supply Sullent		Full range	-	-	600	μΛ	
Maximum Output Voltage(High)	VOH	25°C	4.75	4.84	-	V	RL=600Ω to VDD/2
······································			4.85	4.90	-	-	RL=2kΩ to VDD/2
Maximum Output Voltage(Low)	VOL	25°C	-	170 100	250 150	mV	RL=600Ω to VDD/2 RL=2kΩ to VDD/2
			-	100	150		RL=2kΩ to VDD/2 RL=600Ω to VDD/2
Large Signal Voltage Gain	Av	25°C	- 95	105	-	dB	RL= $2k\Omega$ to VDD/2
Input Common-mode Voltage Range	Vicm	25°C	VSS	-	VDD-0.9	V	VSS to VDD
Common-mode Rejection Ratio	CMRR	25°C	72	90	-	dB	VCM=0.5V
Power supply reject-ratio	PSRR	25°C	75	85	-	dB	VDD=2.7V to 5.0V VCM=1V
Output Source Current *10	Isource	25°C	20	45	-	mA	OUT=0V, short current
Output Sink Current *10	Isink	25°C	20	40	-	mA	OUT=5V, short current
Slew Rate	SR	25°C	-	2.0	-	V/µs	CL=25pF
Gain Bandwidth	GBW	25°C	-	5	-	MHz	CL=25pF, Av=40dB f=1MHz
Phase Margin	θ	25°C	-	45	-	Deg	CL=25pF, Av=40dB
Gain Margin	GM	25°C	-	4.5	-	dB	CL=25pF, Av=40dB
Input Referred Noise Voltage	Vn	25°C	-	42	-	nV/√Hz	f=1kHz
Total Harmonic Distortion + Noise	THD+N	25°C	-	0.01	-	%	OUT=4.1V _{P-P} , f=1kHz RL=10kΩ Av=0dB, DIN-AUDIO

*8 Absolute value

*9 Full range: Ta=-40°C to +85°C

*10 Under the high temperature environment, consider the power dissipation of IC when selecting the output current.

When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

Description of electrical characteristics

Described here are the terms of electric characteristics used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacture's document or general document.

1. Absolute maximum ratings

Absolute maximum rating item indicates the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

- 1.1 Power supply voltage (VDD/VSS) Indicates the maximum voltage that can be applied between the positive power supply terminal and negative power supply terminal without deterioration or destruction of characteristics of internal circuit.
- 1.2 Differential input voltage (Vid) Indicates the maximum voltage that can be applied between non-inverting terminal and inverting terminal without deterioration and destruction of characteristics of IC.
- 1.3 Input common-mode voltage range (Vicm) Indicates the maximum voltage that can be applied to non-inverting terminal and inverting terminal without deterioration or destruction of characteristics. Input common-mode voltage range of the maximum ratings not assures normal operation of IC. When normal Operation of IC is desired, the input common-mode voltage of characteristics item must be followed.
- 1.4 Power dissipation (Pd)

Indicates the power that can be consumed by specified mounted board at the ambient temperature 25°C(normal temperature). As for package product, Pd is determined by the temperature that can be permitted by IC chip in the package (maximum junction temperature) and thermal resistance of the package.

- 2.Electrical characteristics item
 - 2.1 Input offset voltage (Vio)

Indicates the voltage difference between non-inverting terminal and inverting terminal. It can be translated into the input voltage difference required for setting the output voltage at 0 V.

- 2.2 Input offset voltage drift (△Vio/△T) Denotes the ratio of the input offset voltage fluctuation to the ambient temperature fluctuation.
- 2.3 Input offset current (lio)

Indicates the difference of input bias current between non-inverting terminal and inverting terminal.

- 2.4 Input bias current (lb) Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias current at non-inverting terminal and input bias current at inverting terminal.
- 2.5 Circuit current (IDD)

Indicates the IC current that flows under specified conditions and no-load steady status.

- 2.6 Maximum Output Voltage(High) / Maximum Output Voltage(Low) (VOH/VOL) Indicates the voltage range that can be output by the IC under specified load condition. It is typically divided into maximum output voltage High and low. Maximum output voltage high indicates the upper limit of output voltage. Maximum output voltage low indicates the lower limit.
- 2.7 Output source current/output sink current (Isource/Isink)

The maximum current that can be output under specific output conditions, it is divided into output source current and output sink current. The output source current indicates the current flowing out of the IC, and the output sink current the current flowing into the IC.

- 2.8 Large signal voltage gain (Av) Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage. Av = (Output voltage fluctuation) / (Input offset fluctuation)
- 2.9 Input common-mode voltage range (Vicm) Indicates the input voltage range where IC operates normally.
 2.10 Common-mode rejection ratio (CMRR)
- Indicates the ratio of fluctuation of input offset voltage when in-phase input voltage is changed. It is normally the fluctuation of DC.

CMRR = (Change of Input common-mode voltage)/(Input offset fluctuation)

- 2.11 Power supply rejection ratio (PSRR) Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed. It is normally the fluctuation of DC. PSRR= (Change of power supply voltage)/(Input offset fluctuation)
- 2.12 Slew rate (SR)

Indicates the time fluctuation ratio of voltage output when step input signal is applied.

2.13 Gain Band Width (GBW)

Indicates to multiply by the frequency and the gain where the voltage gain decreases 6dB/octave.

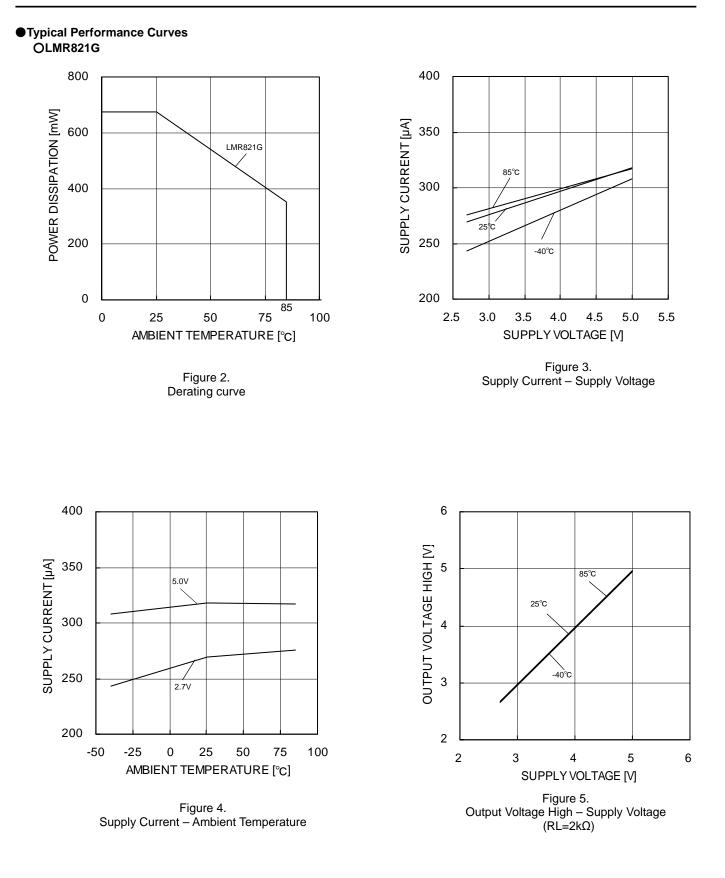
2.14 Phase Margin (θ)

Indicates the margin of phase from 180 degree phase lag at unity gain frequency.

2.15 Gain Margin (GM)

Indicates the difference between 0dB and the gain where operational amplifier has 180 degree phase delay. 2.16 Total harmonic distortion + Noise (THD+N)

- Indicates the fluctuation of input offset voltage or that of output voltage with reference to the change of output voltage of driven channel.
- 2.17 Input referred noise voltage (Vn) Indicates a noise voltage generated inside the operational amplifier equivalent by ideal voltage source connected in series with input terminal.



Typical Performance Curves (Reference data) – Continued
OLMR821G

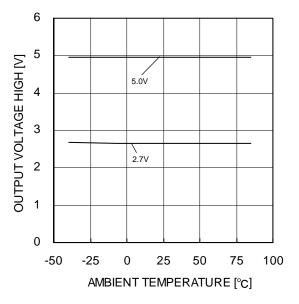
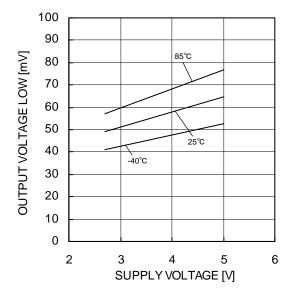
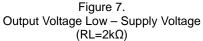
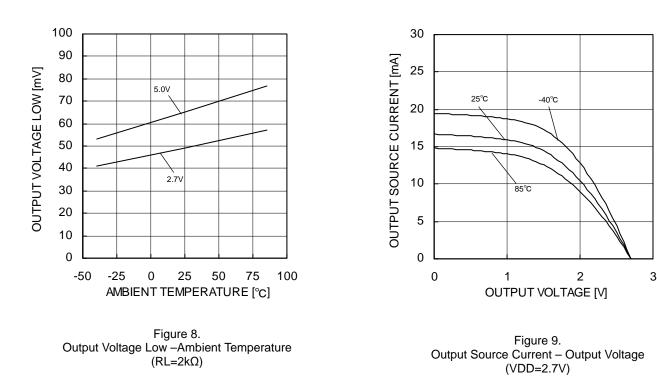


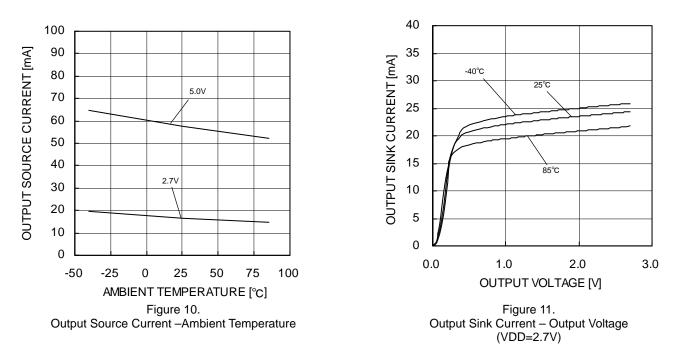
Figure 6. Output Voltage High – Ambient Temperature $(RL=2k\Omega)$







Typical Performance Curves (Reference data) – Continued
OLMR821G



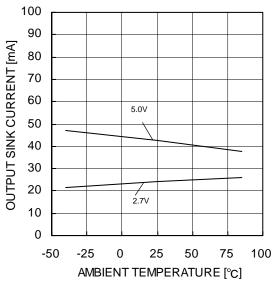


Figure 12. Output Sink Current – Ambient Temperature

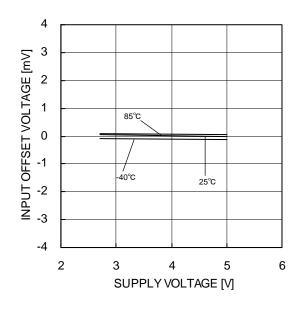


Figure 13. Input Offset Voltage – Supply Voltage

●Typical Performance Curves (Reference data) - Continued OLMR821G

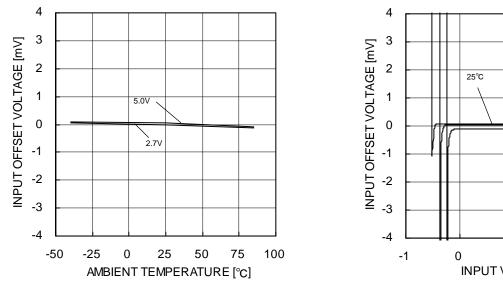
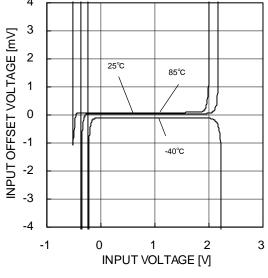
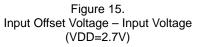


Figure 14. Input Offset Voltage – Ambient Temperature





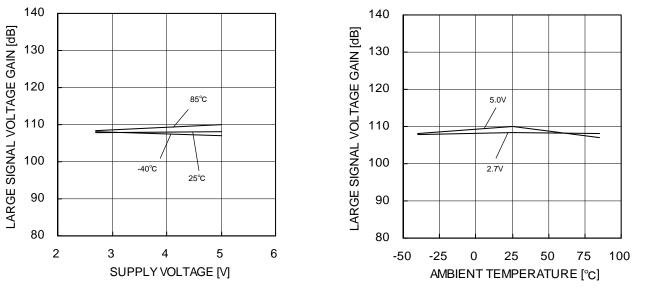


Figure 16. Large Signal Voltage Gain - Supply Voltage

Figure 17. Large Signal Voltage Gain – Ambient Temperature

Typical Performance Curves (Reference data) – Continued OLMR821G

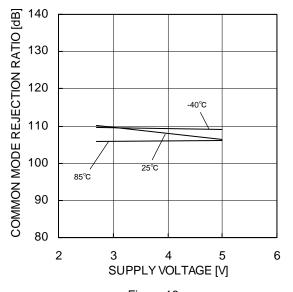


Figure 18. Common Mode Rejection Ratio - Supply Voltage (VDD=2.7V)

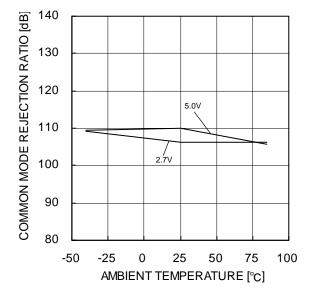
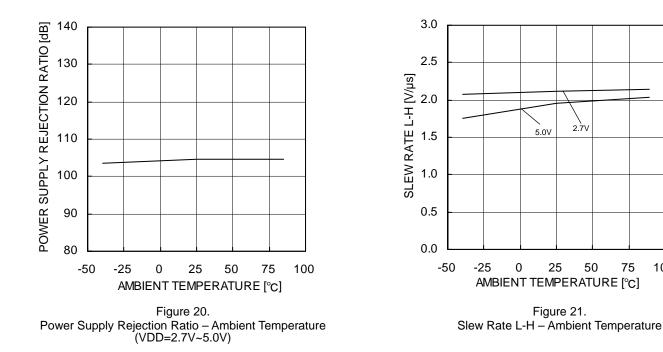


Figure 19. Common Mode Rejection Ratio - Ambient Temperature



(*)The data above is measurement value of typical sample, it is not guaranteed.

100

75

Typical Performance Curves (Reference data) - Continued
OLMR821G

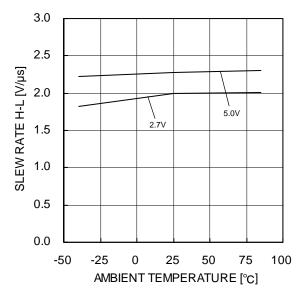


Figure 22. Slew Rate H-L – Ambient Temperature

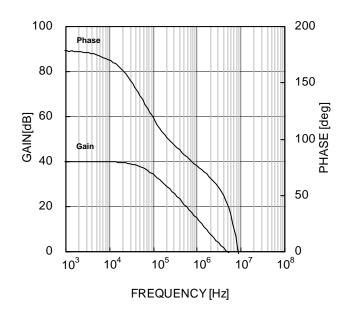


Figure 23. Voltage Gain, Phase – Frequency

Application Information

NULL method condition for Test Circuit 1

VOLE method condition for rest circuit f						VDD	, VSS, I	EK, Vicr	n Unit:V
Parameter	VF	S1	S2	S3	VDD	VSS	EK	Vicm	Calculation
Input Offset Voltage		ON	ON	OFF	3	0	-1.5	3	1
	VF2		ON	ON	3	0	-0.5	1.5	2
Large Signal Voltage Gain	VF3	- ON				0	-2.5		
Common-mode Rejection Ratio	VF4	ON	ON	OFF	3		4.5	0	- 3
(Input Common-mode Voltage Range)	VF5					0	-1.5	3	
Power Supply Rejection Ratio	VF6	ON	ON	OFF	2.5	0	-1.2	0	4
	VF7				5.0			Ŭ	T

- Calculation-

1. Input Offset Voltage (Vio)
$$Vio = \frac{|VF1|}{1+RF/RS}$$
 [V]

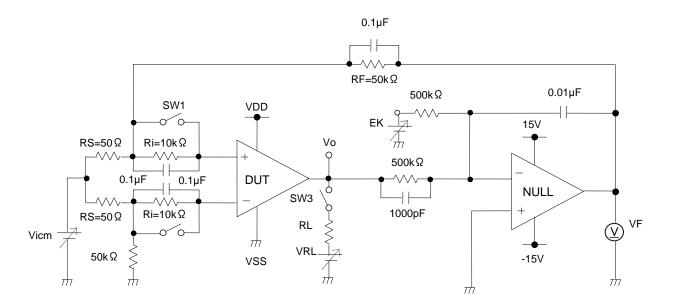
2. Large Signal Voltage Gain(Av)

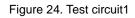
 $Av = 20Log - \frac{2 \times (1 + RF/RS)}{|VF2 - VF3|} [dB]$

3. Common-mode Rejection Ratio (CMRR)

4. Power Supply Rejection Ratio (PSRR)

 $PSRR = 20Log \frac{3.2 \times (1 + RF/RS)}{|VF6 - VF7|} [dB]$





Switch Condition for Test Circuit 2

SW No.	SW1	SW2	SW3	SW4	SW5	SW6	SW7	SW8	SW9	SW10	SW11	SW12
Supply Current	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF
Maximum Output Voltage RL=10kΩ	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF
Output Current	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF
Slew Rate	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	ON
Unity gain Frequency	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	ON	OFF	OFF	ON

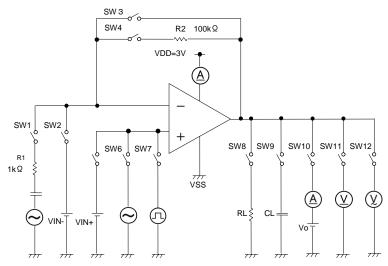


Figure 25. Test circuit2

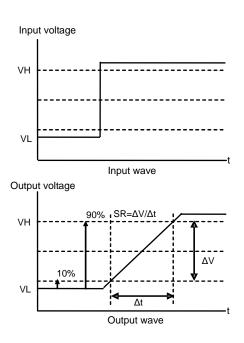


Figure 26. Slew rate input output wave

Examples of circuit OVoltage follower

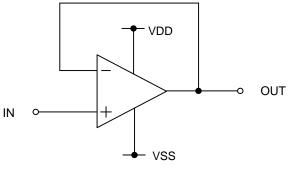


Figure 27. Voltage follower

OInverting amplifier

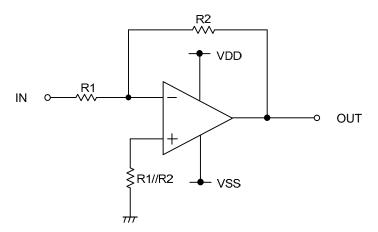


Figure 28. Inverting amplifier circuit

ONon-inverting amplifier

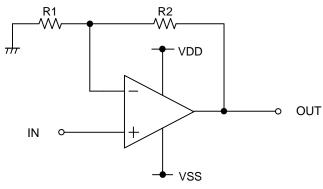


Figure 29. Non-inverting amplifier circuit

Voltage gain is 0dB.

This circuit controls output voltage (OUT) equal input voltage (IN), and keeps OUT with stable because of high input impedance and low output impedance. OUT is shown next expression. OUT=IN

For inverting amplifier, Vi(b) Derating curve voltage gain decided R1 and R2, and phase reversed voltage is output. OUT is shown next expression. $OUT=-(R2/R1) \cdot IN$ Input impedance is R1.

For non-inverting amplifier, IN is amplified by voltage gain decided R1 and R2, and phase is same with IN. OUT is shown next expression. $OUT=(1 + R2/R1) \cdot IN$

This circuit performes high input impedance because Input impedance is operational amplifier's input Impedance.

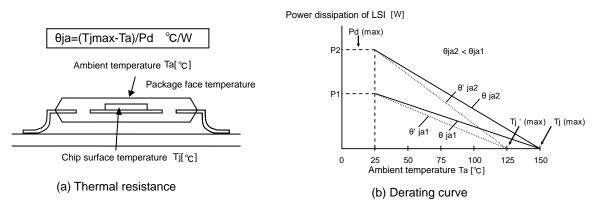
Power Dissipation

Power dissipation (total loss) indicates the power that can be consumed by IC at Ta=25°C(normal temperature).IC is heated when it consumed power, and the temperature of IC ship becomes higher than ambient temperature. The temperature that can be accepted by IC chip depends on circuit configuration, manufacturing process, and consumable power is limited. Power dissipation is determined by the temperature allowed in IC chip (maximum junction temperature) and thermal resistance of package (heat dissipation capability). The maximum junction temperature is typically equal to the maximum value in the storage package (heat dissipation capability). The maximum junction temperature is typically equal to the maximum value in the storage temperature range. Heat generated by consumed power of IC radiates from the mold resin or lead frame of the package. The parameter which indicates this heat dissipation capability (hardness of heat release) is called thermal resistance, represented by the symbol θja°C/W. The temperature of IC inside the package can be estimated by this thermal resistance.

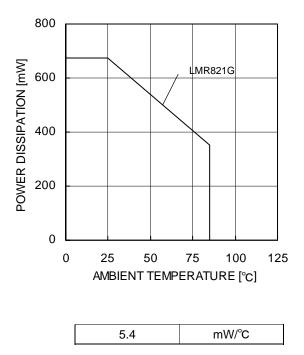
Figure 30. (a) shows the model of thermal resistance of the package. Thermal resistance θ_{ia} , ambient temperature Ta, maximum junction temperature Tjmax, and power dissipation Pd can be calculated by the equation below:

°C/W $\theta_{ja} = (T_{jmax} - T_{a}) / Pd$

(I) Derating curve in Figure 30. (b) indicates power that can be consumed by IC with reference to ambient temperature. Power that can be consumed by IC begins to attenuate at certain ambient temperature. This gradient is determined by thermal resistance θja. Thermal resistance θja depends on chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figure 31. show a derating curve for an example of LMR821







When using the unit above Ta=25°C, subtract the value above per degree°C. Permissible dissipation is the value when FR4 glass epoxy board 70mm × 70mm × 1.6mm (cooper foil area below 3%) is mounted

Figure 31. Derating Curve

Datasheet

Operational Notes

1) Unused circuits

When there are unused circuits it is recommended that they are connected as in Figure 32., setting the non-inverting input terminal to a potential within input common-mode voltage range (Vicm).

2) Applied voltage to the input terminal

For normal circuit operation of voltage comparator, please input voltage for its input terminal within input common mode voltage VDD + 0.3V. Then, regardless of power supply voltage, VSS-0.3V can be applied to input terminals without deterioration or destruction of its characteristics.

3) Power supply (single / dual)

The op-amp operates when the specified voltage supplied is between VDD and VSS. Therefore, the single supply op-amp can be used as dual supply op-amp as well.



Using the unit in excess of the rated power dissipation may cause deterioration in electrical characteristics due to a rise in chip temperature, including reduced current capability. Therefore, please take into consideration the power dissipation (Pd) under actual operating conditions and apply a sufficient margin in thermal design. Refer to the thermal derating curves for more information.

- 5) Short-circuit between pins and erroneous mounting Incorrect mounting may damage the IC. In addition, the presence of foreign particles between the outputs, the output and the power supply, or the output and GND may result in IC destruction.
- Operation in a strong electromagnetic field Operation in a strong electromagnetic field may cause malfunctions.

7) IC handling

Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuations in the electrical characteristics due to piezo resistance effects.

8) Board inspection

Connecting a capacitor to a pin with low impedance may stress the IC. Therefore, discharging the capacitor after every process is recommended. In addition, when attaching and detaching the jig during the inspection phase, ensure that the power is turned OFF before inspection and removal. Furthermore, please take measures against ESD in the assembly process as well as during transportation and storage.

9) The IC destruction caused by capacitive load

The transistors in circuits may be damaged when VDD terminal and VSS terminal is shorted with the charged output terminal capacitor. When IC is used as a operational amplifier or as an application circuit, where oscillation is not activated by an output capacitor, the output capacitor must be kept below 0.1µF in order to prevent the damage mentioned above.

10) Latch up

Be careful of input voltage that exceed the VDD and VSS. When CMOS device have sometimes occur latch up operation. And protect the IC from abnormaly noise

11) Decupling capacitor

Insert the decupling capacitance between VDD and VSS, for stable operation of operational amplifier.

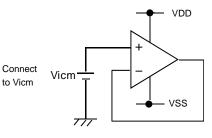
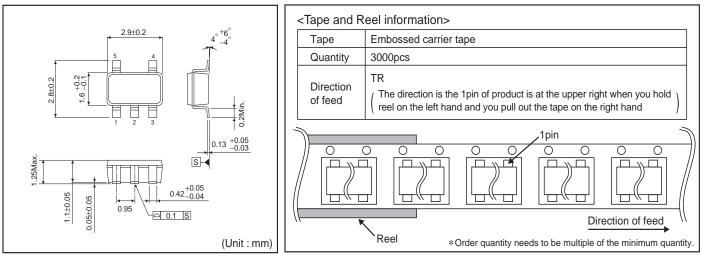
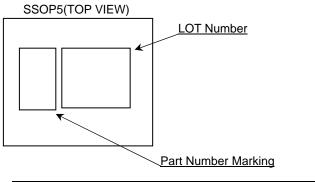


Figure 32. The example of application circuit for unused op-amp

• Physical Dimensions Tape and Reel Information SSOP5

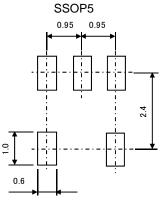


Marking Diagram



Product	Product Name		Marking
LMR821	LMR821 G		L3

Land Pattern



				Unit : mm
PKG	Land Pitch e	Land Space MIE	Land Length ≧ℓ 2	Land Width b2
SSOP5	0.95	2.4	1.0	0.6

Revision History

Date	Revision	Changes
2013.1.18	001	New Release

Notice

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 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4) The Products are not subject to radiation-proof design.
- 5) Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6) In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse) is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7) De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8) Confirm that operation temperature is within the specified range described in the product specification.
- 9) ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1) When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2) In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3) Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4) Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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